Printed by EAST

	Search Terms	Total	USPAT	USOCR	EPO
1	FULL	521273			
2	IMAGE	320873			
3	P-SURFACE	42			
4	SURROUND	81363			
5	VISIBLE	229879			
6	WORLD	64128			
7	(P-SURFACE AND 6)	1			

	U	1	Document ID	Issue Date	Pages
1	☐	☐	US 5487172 A	19960123	508

US 5487/2000 A

	Title	Current OR	Current XRef
1	Transform processor system having reduced processing bandwith	712/32	700/8 ;

	Retrieval Classif	Inventor	S	C	P	2	3	4	5
1		Hyatt, Gilbert P.	☒	☐	☐	☐	☐	☐	☐

Printed by EAST

UserID: THavan

Computer: WS04864

Date: 09/28/2000

Time: 12:44

	U	1	Document ID	Issue Date	Pages
1	☒	☐	US 6018171 A	20000125	12
2	☒	☐	US 5260639 A	19931109	
3	☒	☐	US RE29845 E	19781121	
4	☒	☐	US RE29648 E	19780530	
5	☒	☐	US 4001056 A	19770104	
6	☒	☐	US 3931631 A	19760106	
7	☒	☐	US 3873382 A	19750325	
8	☒	☐	US 3803427 A	19740409	

Title
Shallow junction ferroelectric memory cell having a laterally extending p-n junction and method of making the same
Method for remotely powering a device such as a lunar rover
GaAs.sub.1-x P.sub.x electroluminescent device doped with isoelectronic impurities
Process for the preparation of electroluminescent III-V materials containing isoelectronic impurities
Epitaxial deposition of III-V compounds containing isoelectronic impurities
Gallium phosphide light-emitting diodes
Process for the preparation of semiconductor materials and devices
FREQUENCY MULTIPLIER AND HIGH FREQUENCY GENERATOR

	Current OR	Current XRef	Retrieval Classif	Inventor	S
1	257/295	257/256 ; 438/3 ; 438/957		Hsu, Sheng Teng , et al.	☐
2	322/2R	136/292 ; 244/1R ; 372/43		De Young, Russell J. , et al.	☐
3	257/87			Groves, Warren O. , et al.	☐
4	438/37	117/105 ; 257/101 ; 257/102 ; 313/103R ; 438/45		Groves, Warren O. , et al.	☐
5	438/37	117/105 ; 117/89 ; 117/954 ; 117/955 ; 148/DIG.110 ; 148/DIG.40 ; 148/DIG.99 ; 257/87 ; 313/498 ; 438/45		Groves, Warren O. , et al.	☐
6	257/87	438/46		Groves, Warren O. , et al.	☐
7	438/508	117/89 ; 148/DIG.65 ; 148/DIG.67 ; 148/DIG.72 ; 252/950 ; 252/951 ; 257/79 ; 313/499 ; 438/37 ; 438/925 ; 438/936		Groves, Warren Olley , et al.	☐
8	327/119			Brodzinksy, Albert	☐

	U	1	Document ID	Issue Date	Pages
9	☒	☐	US 3725749 A	19730403	
10	☒	☐	US 3649890 A	19720314	
11	☒	☐	US 3617820 A	19711102	

Title
GaAS P ELECTROLUMINESCENT DEVICE DOPED WITH ISOELECTRONIC IMPURITIES
HIGH BURNOUT RESISTANCE SCHOTTKY BARRIER DIODE
INJECTION-LUMINESCENT DIODES

	Current OR	Current XRef	Retrieval Classif	Inventor	S
9	257/87	148/DIG.107 ; 148/DIG.119 ; 148/DIG.135 ; 148/DIG.49 ; 148/DIG.56 ; 148/DIG.57 ; 148/DIG.59 ; 148/DIG.65 ; 148/DIG.67 ; 148/DIG.72 ; 148/DIG.99 ; 438/37 ; 438/46 ; 438/918		Groves, Warren Olley , et al.	☐
10	257/484	257/428 ; 257/735 ; 257/773 ; 257/785		Howell, Charles M. , et al.	☐
11	257/86	148/DIG.119 ; 148/DIG.56 ; 148/DIG.65 ; 148/DIG.67 ; 257/101 ; 257/103 ; 313/499		Herzog, Arno Henry	☐

Printed by EAST

UserID: THavan

Computer: WS04864

Date: 09/28/2000

Time: 12:51

	Search Terms	Total	USPAT	USOCR	EPO
1	GRAPH	178539			
2	P-SURFACE	42			
3	SURFACE	1588120			
4	(4 AND 3)	11			